

54ABT543 Octal Registered Transceiver with TRI-STATE® Outputs

Check for Samples: [54ABT543](#)

FEATURES

- Back-to-back registers for storage
- Bidirectional data path
- A and B outputs have current sourcing capability of 24 mA and current sinking capability of 48 mA
- Separate controls for data flow in each

direction

- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability
- Standard Military Drawing (SMD) 5962-9231401

DESCRIPTION

The 'ABT543 octal transceiver contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent control of inputting and outputting in either direction of data flow.

Connection Diagram

Figure 1. Pin Assignment for DIP and Flatpak

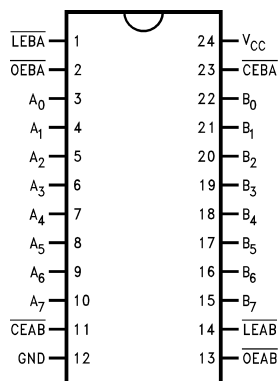
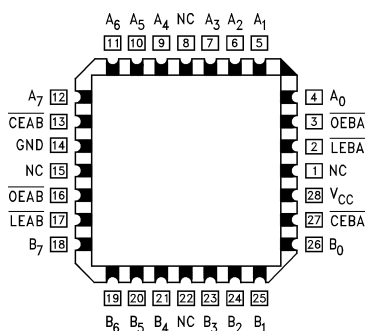


Figure 2. Pin Assignment for LCC



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Pin Functions

Pin Descriptions

Pin Names	Description
\overline{OEAB} , \overline{OEBA}	Output Enable Inputs
\overline{LEAB} , \overline{LEBA}	Latch Enable Inputs
\overline{CEAB} , \overline{CEBA}	Chip Enable Inputs
A ₀ –A ₇	Side A Inputs or TRI-STATE Outputs
B ₀ –B ₇	Side B Inputs or TRI-STATE Outputs

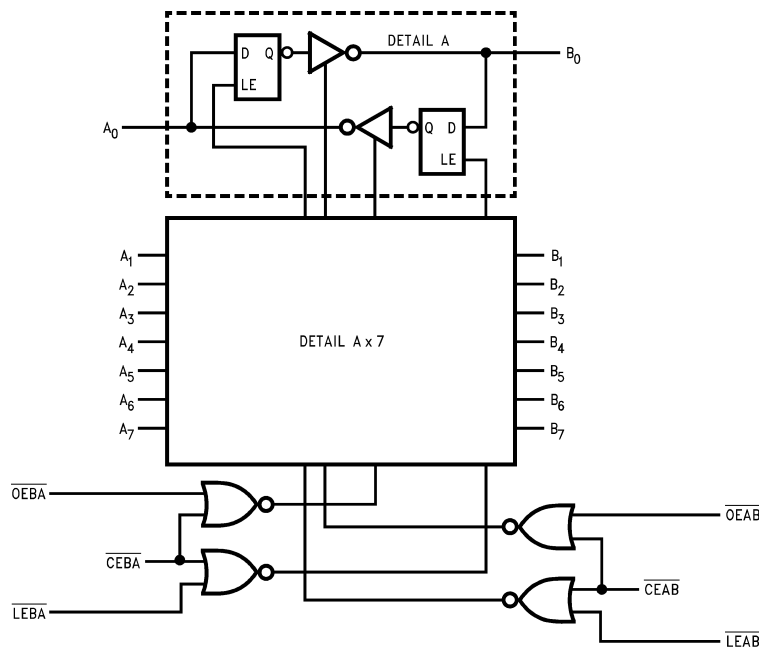
Functional Description

The 'ABT543 contains two sets of D-type latches, with separate input and output controls for each. For data flow from A to B, for example, the A to B Enable (\overline{CEAB}) input must be low in order to enter data from the A port or take data from the B port as indicated in the Data I/O Control Table. With \overline{CEAB} low, a low signal on (\overline{LEAB}) input makes the A to B latches transparent; a subsequent low to high transition of the \overline{LEAB} line puts the A latches in the storage mode and their outputs no longer change with the A inputs. With \overline{CEAB} and \overline{OEAB} both low, the B output buffers are active and reflect the data present on the output of the A latches. Control of data flow from B to A is similar, but using the \overline{CEBA} , \overline{LEBA} and \overline{OEBA} .

Table 1. Data I/O Control Table

Inputs			Latch Status	Output Buffers
\overline{CEAB}	\overline{LEAB}	\overline{OEAB}		
H	X	X	Latched	High Z
X	H	X	Latched	—
L	L	X	Transparent	—
X	X	H	—	High Z
L	X	L	—	Driving

Logic Diagram





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings ⁽¹⁾

Storage Temperature	-65°C to +150°C
Ambient Temperature under Bias	-55°C to +125°C
Junction Temperature under Bias	
Ceramic	-55°C to +175°C
V _{CC} Pin Potential to	
Ground Pin	-0.5V to +7.0V
Input Voltage ⁽²⁾	-0.5V to +7.0V
Input Current ⁽²⁾	-30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disable or Power-Off State	-0.5V to +5.5V
in the HIGH State	-0.5V to V _{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I _{OL} (mA)
DC Latchup Source Current	-500 mA
Over Voltage Latchup (I/O)	10V

(1) Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

(2) Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	-55°C to +125°C
Supply Voltage	
Military	+4.5V to +5.5V
Minimum Input Edge Rate	(ΔV/Δt)
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100 mV/ns

DC Electrical Characteristics

Symbol	Parameter	ABT543			Units	V _{CC}	Conditions
		Min	Typ	Max			
V _{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V _{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V _{CD}	Input Clamp Diode Voltage			-1.2	V	Min	I _{IN} = -18 mA (Non I/O Pins)
V _{OH}	Output HIGH Voltage	54ABT	2.5				I _{OH} = -3 mA, (A _n , B _n)
		54ABT	2.0		V	Min	I _{OH} = -24 mA, (A _n , B _n)
V _{OL}	Output LOW Voltage	54ABT		0.55	V	Min	I _{OL} = 48 mA, (A _n , B _n)
V _{ID}	Input Leakage Test		4.75		V	0.0	I _{ID} = 1.9 μA, (Non-I/O Pins)
							All Other Pins Grounded
I _{IH}	Input HIGH Current			5	μA	Max	V _{IN} = 2.7V (Non-I/O Pins) ⁽¹⁾
							V _{IN} = V _{CC} (Non-I/O Pins)
I _{BVI}	Input HIGH Current Breakdown Test			7	μA	Max	V _{IN} = 7.0V (Non-I/O Pins)
I _{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	μA	Max	V _{IN} = 5.5V (A _n , B _n)
I _{IL}	Input LOW Current			-5	μA	Max	V _{IN} = 0.5V (Non-I/O Pins) ⁽¹⁾
							V _{IN} = 0.0V (Non-I/O Pins)
I _{IH} + I _{OZH}	Output Leakage Current			50	μA	0V–5.5V	V _{OUT} = 2.7V (A _n , B _n); OEAB or CEAB = 2V
I _{IL} + I _{OZL}	Output Leakage Current			-50	μA	0V–5.5V	V _{OUT} = 0.5V (A _n , B _n); OEAB or CEAB = 2V
I _{OS}	Output Short-Circuit Current	-100		-275	mA	Max	V _{OUT} = 0V (A _n , B _n)
I _{CEX}	Output HIGH Leakage Current			50	μA	Max	V _{OUT} = V _{CC} (A _n , B _n)
I _{ZZ}	Bus Drainage Test			100	μA	0.0V	V _{OUT} = 5.5V (A _n , B _n);
							All Others GND
I _{CC LH}	Power Supply Current			50	μA	Max	All Outputs HIGH
I _{CC L}	Power Supply Current			30	mA	Max	All Outputs LOW
I _{CC Z}	Power Supply Current			50	μA	Max	Outputs TRI-STATE
							All Others at V _{CC} or GND
I _{CCT}	Additional I _{CC} /Input			2.5	mA	Max	V _I = V _{CC} - 2.1V
							All Others at V _{CC} or GND
I _{CCD}	Dynamic I _{CC}	No Load					Outputs Open, CEAB
		⁽¹⁾		0.18	mA/MHz	Max	and OEAB = GND, CEBA = V _{CC} , One Bit Toggling, 50% Duty Cycle, ⁽²⁾

(1) Guaranteed but not tested.

(2) For 8-bit toggling. I_{CCD} < 1.4 mA/MHz.**DC Electrical Characteristics**

Symbol	Parameter	Min	Max	Units	V _{CC}	Conditions
						C _L = 50 pF, R _L = 500Ω
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}		1.1	V	5.0	T _A = 25°C ⁽¹⁾
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}		-0.45	V	5.0	T _A = 25°C ⁽¹⁾

(1) Max number of outputs defined as (n). n - 1 data inputs are driven 0V to 3V. One output at LOW.

AC Electrical Characteristics

		54ABT			
		$T_A = -55^\circ\text{C to } +125^\circ\text{C}$			Fig.
Symbol	Parameter	$V_{CC} = 4.5\text{V} - 5.5\text{V}$		Units	No.
		$C_L = 50\text{ pF}$			
		Min	Max		
t_{PLH}	Propagation Delay	1.6	6.4	ns	Figure 4
t_{PHL}	A_n to B_n or B_n to A_n	1.6	6.2		
t_{PLH}	Propagation Delay				
t_{PHL}	\overline{LEAB} to B_n , \overline{LEBA} to A_n	1.6	6.6	ns	Figure 4
	\overline{OEBA} or \overline{OEAB} to A_n or B_n	1.6	6.4		
t_{PZH}	Enable Time				
t_{PZL}	\overline{LEAB} to B_n , \overline{LEBA} to A_n	1.3	6.4	ns	Figure 6
	\overline{OEBA} or \overline{OEAB} to A_n or B_n	1.8	7.4		
t_{PHZ}	Disable Time	2.0	7.2	ns	Figure 6
t_{PLZ}	\overline{CEBA} or \overline{CEAB} to A_n or B_n	1.5	7.0		

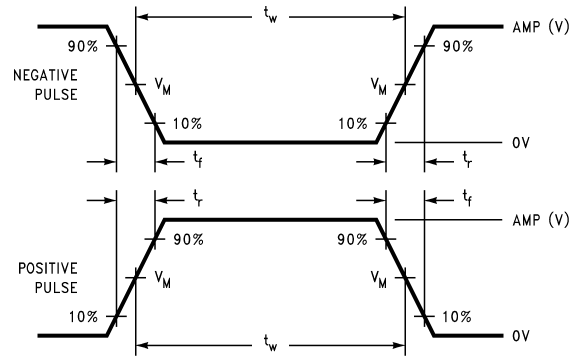


Figure 3. $V_M = 1.5V$
Input Pulse Requirements

Test Input Signal Requirements

Amplitude	Rep. Rate	t_w	t_r	t_f
3V	1 MHz	500 ns	2.5 ns	2.5 ns

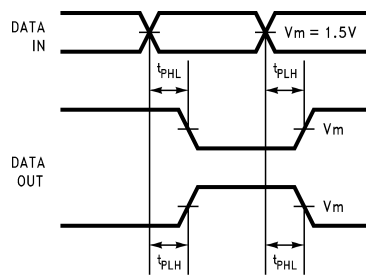


Figure 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

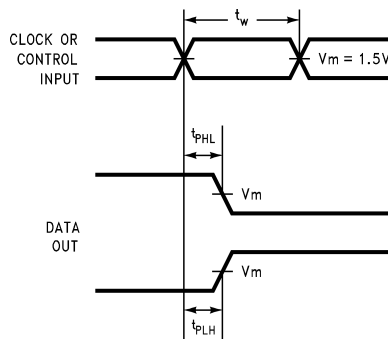


Figure 5. Propagation Delay,
Pulse Width Waveforms

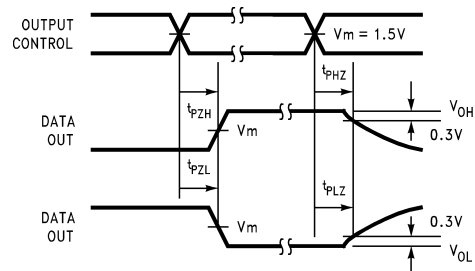


Figure 6. TRI-STATE Output HIGH and LOW Enable and Disable Times

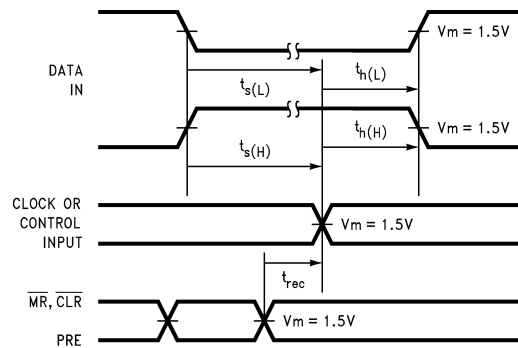


Figure 7. Setup Time, Hold Time and Recovery Time Waveforms

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